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STMicroelectronics BD238

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**BD238** 

## Low voltage PNP power transistor

### **Features**

- Low saturation voltage
- PNP transistor

## **Applications**

■ Audio, power linear and switching applications

## **Description**

The device is manufactured in planar technology with "Base Island" layout. The resulting transistor shows exceptional high gain performance coupled with very low saturation voltage. The NPN type is BD237.

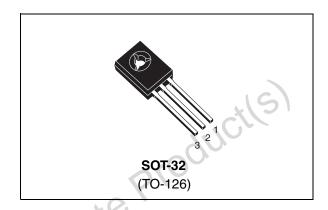


Figure 1. Internal schematic diagram

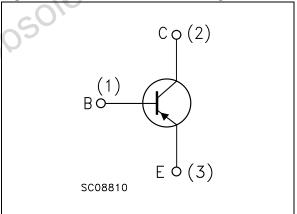


Table 1. Device summary

Order code	Marking	Package	Packaging
BD238	BD238	SOT-32	Tube

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### **Absolute maximum ratings**

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# 1 Absolute maximum ratings

Table 2. Absolute maximum ratings

Collector-base voltage ( $I_E = 0$ )  Collector-emitter voltage ( $R_{BE} = 1 \text{ k}\Omega$ )		
Collector-emitter voltage (Bpc = 1 kO)	-100	V
Concetor critical voltage (LIBE - LIZZ)	-100	V
Collector-emitter voltage (I <sub>B</sub> = 0)	-80	V
Emitter-base voltage (I <sub>C</sub> = 0)	-5	V
Collector current	-2	Α
Collector peak current (t <sub>p</sub> < ms)	-6	Α
Total dissipation at T <sub>case</sub> = 25 °C	25	W
Storage temperature	-65 to 150	°C
Max. operating junction temperature	150	°C
roduct(s)		
	Collector current  Collector peak current (t <sub>p</sub> < ms)  Total dissipation at T <sub>case</sub> = 25 °C	





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**Electrical characteristics** 

## 2 Electrical characteristics

(T<sub>case</sub> = 25 °C; unless otherwise specified)

Table 3. Electrical characteristics

Symbol	Parameter	Test conditions	Min.	Тур.	Max.	Unit
1	Collector cut-off current	V <sub>CB</sub> = -100 V			-0.1	mA
I <sub>CBO</sub>	(I <sub>E</sub> = 0)	$V_{CB} = -100 \text{ V T}_{c} = 150 ^{\circ}\text{C}$		-	-2	mA
I <sub>EBO</sub>	Emitter cut-off current (I <sub>C</sub> = 0)	V <sub>EB</sub> = -5 V		-	-1 -	mA
V <sub>CEO(sus)</sub> <sup>(1)</sup>	Collector-emitter sustaining voltage (I <sub>B</sub> = 0)	I <sub>C</sub> = -100 mA	-80	NO.		٧
V <sub>CE(sat)</sub> <sup>(1)</sup>	Collector-emitter saturation voltage	$I_C = -1 A$ $I_B = -0.1 A$		ı	-0.6	٧
V <sub>BE(on)</sub> <sup>(1)</sup>	Base-emitter on voltage	$I_C = -1 A$ $V_{CE} = -2 V$		1	-1.3	V
h <sub>FE</sub> <sup>(1)</sup>	DC current gain	$I_C = -150 \text{ mA}$ $V_{CE} = -2 \text{ V}$ $I_C = -1 \text{ A}$ $V_{CE} = -2 \text{ V}$	40 25	-		

<sup>1.</sup> Pulsed duration = 300 μs, duty cycle = 1.5 %.



Electrical characteristics

## 2.1 Electrical characteristic (curves)

Figure 2. Safe operating area

Figure 3. Derating curves

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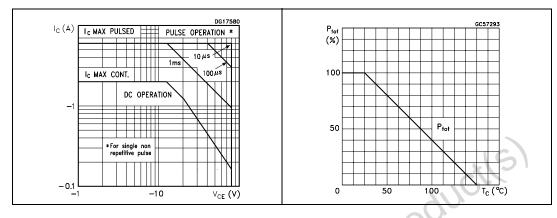


Figure 4. DC current gain ( $V_{CE} = -2 V$ ) Figure 5. DC current gain ( $V_{CE} = -4 V$ )

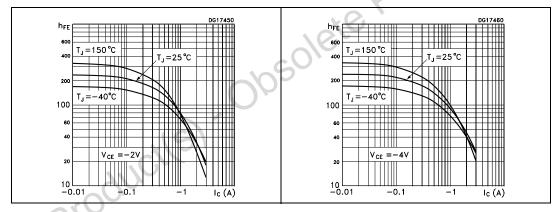
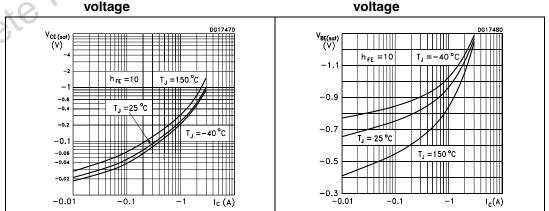


Figure 6. Collector-emitter saturation Figure 7. Base-emitter saturation voltage voltage



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**Electrical characteristics** 

Figure 8. Base-emitter on voltage

V<sub>BE(on)</sub> (V) V<sub>CE</sub> = -4V T<sub>J</sub> = -40 °C (17490 °C) (174

Figure 9. Resistive load switching time (on)

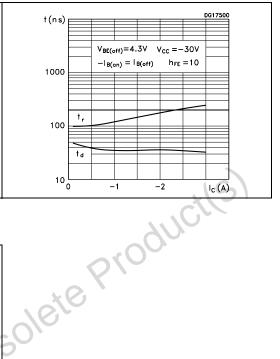
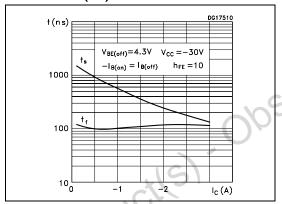
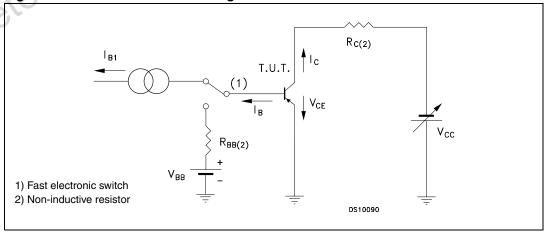


Figure 10. Resistive load switching time (off)



### 2.2 Test circuit

Figure 11. Resistive load switching test circuit





Package mechanical data

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## 3 Package mechanical data

In order to meet environmental requirements, ST offers these devices in different grades of ECOPACK<sup>®</sup> packages, depending on their level of environmental compliance. ECOPACK<sup>®</sup> specifications, grade definitions and product status are available at: www.st.com. ECOPACK<sup>®</sup> is an ST trademark.



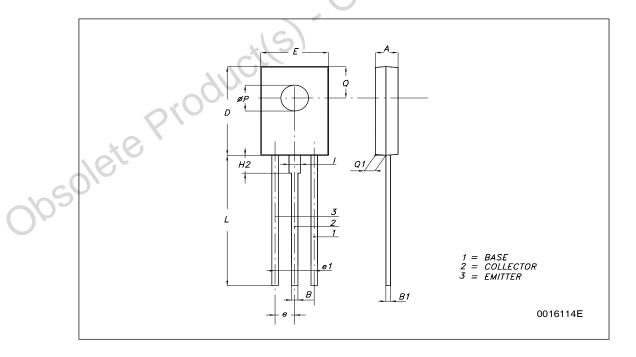


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### Package mechanical data

SOT-32 (TO-126) mechanical data
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DIM.	mm.				
DIIVI.	MIN.	TYP	MAX.		
Α	2.4		2.9		
В	0.64		0.88		
B1	0.39		0.63		
D	10.5		11.05		
E	7.4		7.8		
е	2.04	2.29	2.54		
e1	4.07	4.58	5.08		
L	15.3		16		
Р	2.9		3.2		
Q		3.8			
Q1	1	1/0	1.52		
H2		2.15			
I		1.27			





Revision History BD238

# 4 Revision History

Table 4. Document revision history

Date	Revision	Changes
03-Jun-2009	1	Initial release







### Distributor of STMicroelectronics: Excellent Integrated System Limited

Datasheet of BD238 - TRANS PNP 80V 2A SOT-32

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